UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO.

: 6,918,072 B2

DATED

: July 12, 2005

INVENTOR(S): Timothy B. Cowles et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page,

Item [56], References Cited, OTHER PUBLICATIONS.

"Micron Technology, Inc.; "Synchronous DRAM" Data Sheets; 128Mb: x32 SDRAM: x32 DRAM, 128MbSDRAMx32, p65—Rev. Sep. 2000, pp. 1-52." should read -- Micron Technology, Inc.; "Synchronous DRAM" Data Sheets; 128Mb: x32 SDRAM, 128Mb: x32 DRAM, 128MbSDRAMx32, p65 - Rev. Sep. 2000, pp. 1-52. --.

Column 1,

Line 55, "256 chip" should read -- 256 chips --;

Column 13,

Line 2, "address" should read -- addresses --;

Column 14,

Line 39, "illustrates" should read -- illustrate --;

Line 18, "redundant, planes" should read -- redundant planes --; and

Column 22,

Line 31, "scoring" should read -- storing --.

Signed and Sealed this

Page 1 of 1

Twenty-eighth Day of February, 2006

JON W. DUDAS Director of the United States Patent and Trademark Office